TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC4051AP,TC74HC4051AF,TC74HC4051AFT TC74HC4052AP,TC74HC4052AF,TC74HC4052AFT TC74HC4053AP,TC74HC4053AF,TC74HC4053AFT

TC74HC4051AP/AF/AFT

8-Channel Analog Multiplexer/Demultiplexer

TC74HC4052AP/AF/AFT

Dual 4-Channel Analog Multiplexer/Demultiplexer

TC74HC4053AP/AF/AFT

Triple 2-Channel Analog Multiplexer/Demultiplexer

The TC74HC4051A/4052A/4053A are high speed CMOS ANALOG MULTIPLEXER/DEMULTIPLEXER fabricated with silicon gate C^2MOS technology. They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The TC74HC4051A has an 8 channel configuration, the TC74HC4052A has a 4 channel \times 2 configuration and the TC74HC4053A has a 2 channel \times 3 configuration.

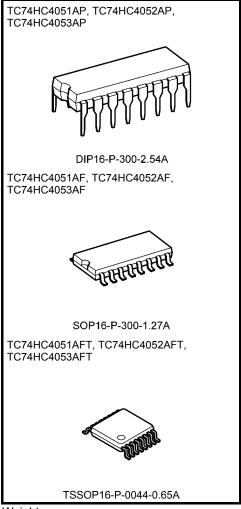
The digital signal to the control terminal turns "ON" the corresponding switch of each channel a large amplitude signal ($V_{\rm CC}-V_{\rm EE}$) can then be switched by the small logical amplitude ($V_{\rm CC}-G_{\rm ND}$) control signal.

For example, in the case of $V_{\rm CC}$ = 5 V, GND = 0 V, $V_{\rm EE}$ = -5 V, signals between -5 V and +5 V can be switched from the logical circuit with a single power supply of 5 V. As the ON-resistance of each switch is low, they can be connected to circuits with low input impedance.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 15 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$, $V_{EE} = 0 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_a = 25^{\circ}C$
- High noise immunity: VNIH = VNIL = 28% VCC (min)
- Low ON resistance: $R_{ON} = 50 \Omega$ (typ.) at $V_{CC} V_{EE} = 9 V$
- High noise immunity: THD = 0.02% (typ.) at $V_{CC} V_{EE} = 9 \text{ V}$
- Pin and function compatible with 4051/4052/4053B

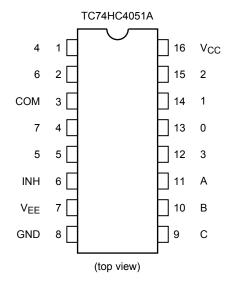


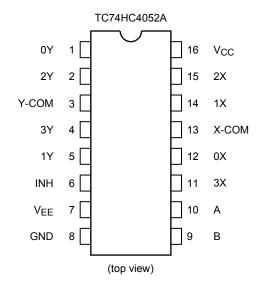
Weight

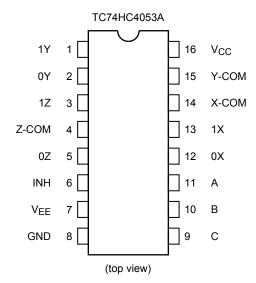
DIP16-P-300-2.54A : 1.00 g (typ.) SOP16-P-300-1.27A : 0.18 g (typ.) TSSOP16-P-0044-0.65A : 0.06 g (typ.)



Pin Assignment



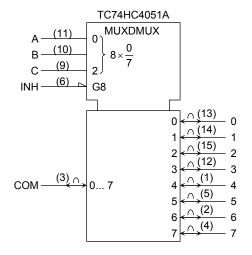


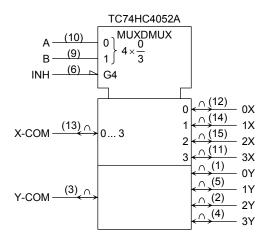


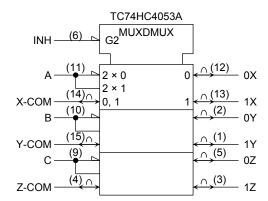
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IEC Logic Symbol







Truth Table

Control Inputs				"ON" Channel				
Inhibit	C*	В	Α	HC4051A	HC4052A	HC4053A		
L	L	L	L	0	0X, 0Y	0X, 0Y, 0Z		
L	L	L	Н	1	1X, 1Y	1X, 0Y, 0Z		
L	L	Н	L	2	2X, 2Y	0X, 1Y, 0Z		
L	L	Н	Н	3	3X, 3Y	1X, 1Y, 0Z		
L	Н	L	L	4	_	0X, 0Y, 1Z		
L	Н	L	Н	5	_	1X, 0Y, 1Z		
L	Н	Н	L	6	_	0X, 1Y, 1Z		
L	Н	Н	Н	7	_	1X, 1Y, 1Z		
Н	Х	Х	Х	None	None	None		

X: Don't care

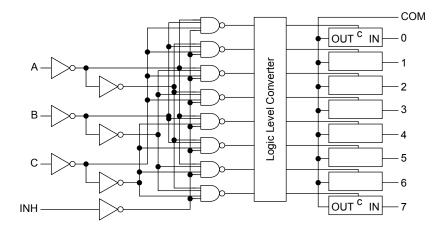
*: Except HC4052A

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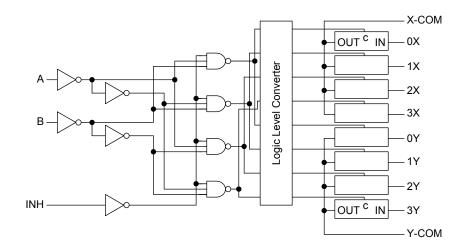


System Diagram

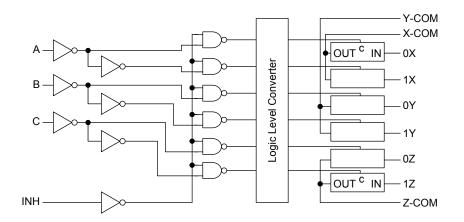
TC74HC4051A



TC74HC4052A



TC74HC4053A





Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	–0.5 to 7	V
Supply voltage range	V _{CC} -V _{EE}	-0.5 to 13	V
Control input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
Switch I/O voltage	V _{I/O}	V _{EE} – 0.5 to V _{CC} + 0.5	V
Control input diode current	I _{ICK}	±20	mA
I/O diode current	lok	±20	mA
Switch through current	ΙΤ	±25	mA
DC V _{CC} or ground current	Icc	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP, TSSOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	2 to 6	V
Supply voltage range	V _{EE}	−6 to 0	V
Supply voltage range	V _{CC} -V _{EE}	2 to 12	V
Control input voltage	V _{IN}	0 to V _{CC}	V
Switch I/O voltage	V _{I/O}	V _{EE} to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
		0 to 1000 (V _{CC} = 2.0 V)	
Control input rise and fall time	t _r , t _f	0 to 500 (V _{CC} = 4.5 V)	ns
		0 to 400 (V _{CC} = 6.0 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused control inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
	•	V _{EE} (V)		V _{CC} (V)	Min	Тур.	Max	Min	Max	
				2.0	1.50	_	_	1.50	_	
High-level control input voltage	V_{IHC}	_		4.5	3.15	_	_	3.15	_	V
,				6.0	4.20		_	4.20	_	
				2.0	_	_	0.50	_	0.50	
Low-level control input voltage	V_{ILC}	_		4.5	_	_	1.35	_	1.35	V
	6.0 — — 1.80 —	_	1.80							
		$V_{IN} = V_{ILC}$ or V_{IHC}	GND	4.5	_	85	180	_	225	
		$V_{I/O} = V_{CC}$ to V_{EE}	-4.5	4.5	_	55	120	_	150	
	R _{ON}	$I_{I/O} \le 2 \text{ mA}$	-6.0	6.0	_	50	100	_	125	
ON resistance		$V_{IN} = V_{ILC}$ or V_{IHC} $V_{I/O} = V_{CC}$ or V_{EE}	GND	2.0	_	150	_	_	_	Ω
			GND	4.5	_	70	150	_	190	
		I _{I/O} ≤ 2 mA	-4.5	4.5	_	50	100	_	125	
		1//0 = 2 11/4	-6.0	6.0	_	45	80	_	100	
Difference of ON		$V_{IN} = V_{ILC}$ or V_{IHC}	GND	4.5	_	10	30	_	35	
resistance between	ΔR_{ON}	$V_{I/O} = V_{CC}$ to V_{EE}	-4.5	4.5	_	5	12	_	15	Ω
switches		$I_{I/O} \leq 2 \ mA$	-6.0	6.0		5	10	_	12	
Input/output leakage		$V_{OS} = V_{CC}$ or GND	GND	6.0 6.0		_ _	±60	_	±600	
current	l _{OFF}	$V_{IS} = GND \text{ or } V_{CC}$	-6.0				±100		±1000	nA
(switch off)		$V_{IN} = V_{ILC}$ or V_{IHC}		0.0			±100		±1000	
Switch input leakage	V	V _{OS} = V _{CC} or GND	GND	6.0	_	_	±60	_	±600	
current	I_{IZ}	V _{IN} = V _{ILC} or V _{IHC}	-6.0	6.0	_	_ _	±100	_	±1000	nA
(switch on)			OND	0.0			10.4		14.0	•
Control input current	I _{IN}	$V_{IN} = V_{CC}$ or GND	GND	6.0			±0.1		±1.0	μΑ
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND	GND	6.0	_		4.0	_	40.0	μА
Current			-6.0	6.0	_		8.0	_	80.0	



AC Characteristics ($C_L = 50 \text{ pF}$, input: $t_r = t_f = 6 \text{ ns}$, GND = 0 V)

Charactaristics	Symbol		Test Condition		-	Га = 25°(C		a = o 85°C	Unit	
Characteristics	Syllibol			V _{EE} (V)	V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
				GND	2.0	_	25	60	_	75	
Phase difference between input and output		A II 4:		GND	4.5	_	6	12	_	15	
	ΦΙ/Ο	All types		GND	6.0	_	5	10	_	13	ns
				-4.5	4.5		4	_	_	_	
				GND	2.0		64	225	_	280	
		4051	(Note 1)	GND	4.5	_	18	45	_	56	
		4031	(Note 1)	GND	6.0	_	15	38	_	48	
				-4.5	4.5		18	_	_	_	
				GND	2.0	_	64	225	_	280	
Output enable time	t _{pZL}	4052	(Note 1)	GND	4.5	_	18	45	_	56	ns
Output enable time	t _{pZH}	4032	(Note 1)	GND	6.0	_	15	38	_	48	113
				-4.5	4.5		18	_	_	_	
				GND	2.0	_	50	225	_	280	
		4053	(Note 1)	GND	4.5	_	14	45	_	56	
		7000		GND	6.0	_	12	38	_	48	
				-4.5	4.5		14	_	_	_	
				GND	2.0	_	100	250	_	315	
		4051	(Note 1)	GND	4.5	_	33	50	_	63	ns
				GND	6.0	_	28	43	_	54	
				-4.5	4.5		29	_	_	_	
				GND	2.0	_	100	250	_	315	
Output disable time	t_{pLZ}	4052	(Note 1)	GND	4.5	_	33	50	_	63	
	t _{pHZ}			GND	6.0	_	28	43	_	54	
				-4.5	4.5		29	_	_	_	
				GND	2.0	_	95	225	_	280	
		4053	(Note 1)	GND	4.5	_	30	45	_	56	
			,	GND	6.0	_	26	38		48	
				-4.5	4.5		26	_	_	_	
Control input capacitance	C _{IN}	All types		_	_		5	10	_	10	pF
COMMONI to making al		4051				_	36	70	_	70	
COMMON terminal capacitance	C _{IS}	4052		-5.0	5.0	_	19	40	_	40	pF
•		4053				_	11	20	_	20	
CMITOLIA		4051				_	7	15	_	15	
SWITCH terminal capacitance	Cos	4052		-5.0	5.0	_	7	15	_	15	pF
		4053				_	7	15	_	15	
Coadthrough		4051				_	0.95	2	_	2	
Feedthrough capacitance	C _{IOS}	4052		-5.0	5.0	_	0.85	2	_	2	pF
		4053				_	0.75	2	_	2	
Dower dice:		4051	_			_	70	_	_	_	
Power dissipation capacitance	C _{PD}	4052	(Note 2)	GND	5.0	_	71	_	_	_	pF
		4053				_	67	<u> </u>		<u> </u>	

Note 1: $R_L = 1 k\Omega$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance of IC which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$



Analog Switch Characteristics (GND = 0 V, Ta = 25°C) (Note 1)

		Test Condition						
Characteristics	Symbol				V _{EE} (V)	V _{CC} (V)	Тур.	Unit
Sine wave distortion (T.H.D)		$R_L=10~k\Omega,$ $C_L=50~pF$ $f_{IN}=1~kHz$ Adjust f_{IN} voltage to obtain	$V_{IN} = 8$	4.0 V _{p-p} 3.0 V _{p-p} 11.0 V _{p-p} (Note 2) (Note 3)	-2.25 -4.5 -6.0	2.25 4.5 6.0 2.25	0.025 0.020 0.018 120 45 70 95	%
Frequency response (switch on)	fmax	OdBm at V_{OS} Increase f_{IN} frequency until dB meter reads -3 dB $R_L = 50 \Omega$, $C_L = 10 pF$ $f_{IN} = 1 \text{ MHz}$, sine wave	All 4051 4053 All 4051 4052 4053	(Note 2) (Note 3) (Note 2) (Note 3)	-4.5	6.0	190 70 110 150 200 85 140 190	MHz
Feed through attenuation (switch off) Crosstalk		V_{IN} is centered at $(V_{CC} - V_{EE})/2$ Adjust input for 0dBm $R_L = 600~\Omega,~C_L = 50~pF$ $f_{IN} = 1~MHz,~sine~wave$ $R_L = 600~\Omega,~C_L = 50~pF$			-2.25 -4.5 -6.0 -2.25 -4.5	2.25 4.5 6.0 2.25 4.5	-50 -50 -50 -60 140	dB mV
(control input to signal output) Crosstalk (between any switches)		f_{IN} = 1 MHz, square wave Adjust V_{IN} to obtain 0dBm at R_L = 600 Ω , C_L = 50 pF f_{IN} = 1 MHz, sine wave	-6.0 -2.25 -4.5 -6.0	6.0 2.25 4.5 6.0	200 -50 -50 -50	dB		

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Note 1: These characteristics are determined by design of devices.

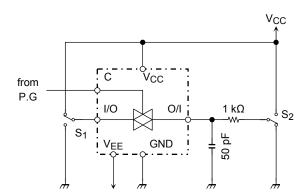
Note 2: Input COMMON terminal, and measured at SWITCH terminal.

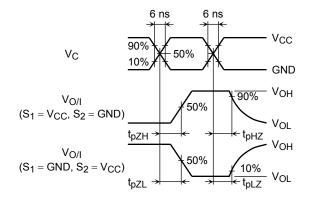
Note 3: Input SWITCH terminal, and measured at COMMON terminal.



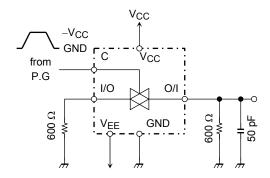
Switching Characteristics Test Circuits

$1. \quad t_{pLZ},\, t_{pHZ},\, t_{pZL},\, t_{pZH}$

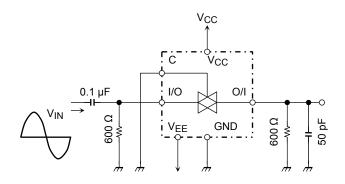




2. Cross Talk (control input-switch output) $f_{IN} = 1$ MHz duty = 50% $t_r = t_f = 6$ ns

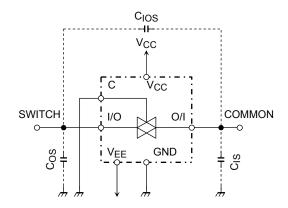


3. Feedthrough Attenuation

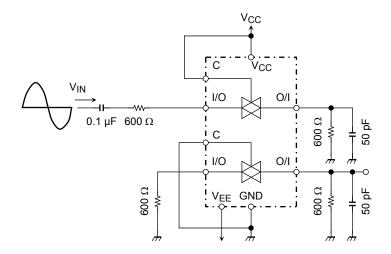


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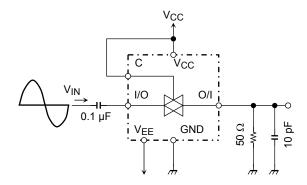
4. CIOS, CIS, COS



5. Cross Talk (between any two switches)

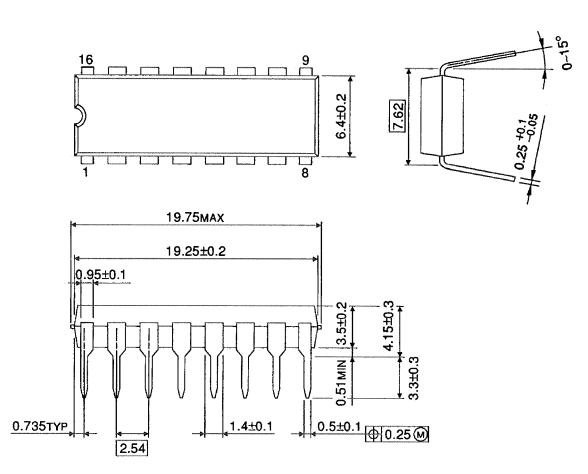


6. Frequency Response (switch on)



Package Dimensions

DIP16-P-300-2.54A Unit: mm

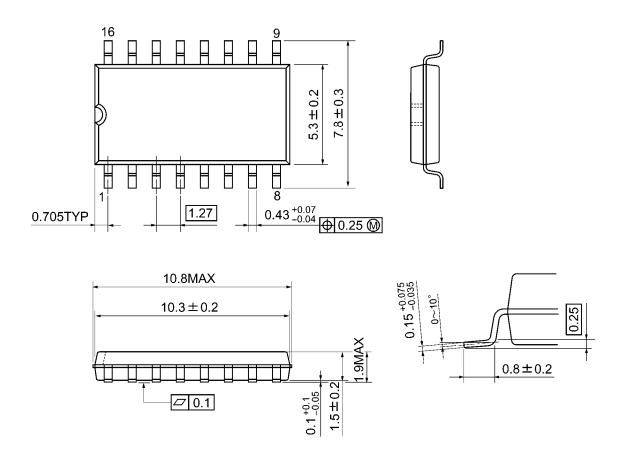


Weight: 1.00 g (typ.)



Package Dimensions

SOP16-P-300-1.27A Unit: mm

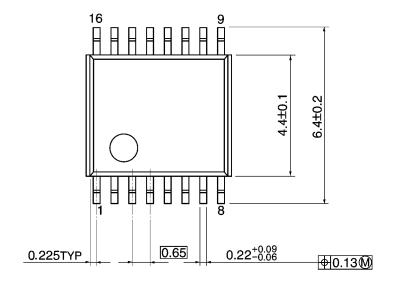


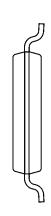
Weight: 0.18 g (typ.)

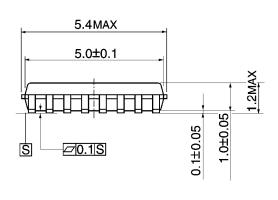
Package Dimensions

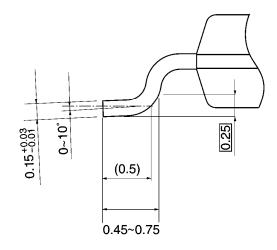
TSSOP16-P-0044-0.65A

Unit: mm









Weight: 0.06 g (typ.)



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